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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I ² S, LCD, POR, PWM, WDT
Number of I/O	63
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-TQFP
Supplier Device Package	80-TQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b540f64gq80-a

- **Timers/Counters**
 - 2 × 16-bit Timer/Counter
 - 3 or 4 Compare/Capture/PWM channels (4 + 4 on one timer instance)
 - Dead-Time Insertion on one timer instance
 - 2 × 32-bit Timer/Counter
 - 32-bit Real Time Counter and Calendar (RTCC)
 - 32-bit Ultra Low Energy CRYOTIMER for periodic wakeup from any Energy Mode
 - 16-bit Low Energy Timer for waveform generation
 - 16-bit Pulse Counter with asynchronous operation
 - Watchdog Timer with dedicated RC oscillator
- **Low Energy Sensor Interface (LESENSE)**
 - Autonomous sensor monitoring in Deep Sleep Mode
 - Wide range of sensors supported, including LC sensors and capacitive buttons
 - Up to 16 inputs
- **Ultra efficient Power-on Reset and Brown-Out Detector**
- **Debug Interface**
 - 2-pin Serial Wire Debug interface
 - 4-pin JTAG interface
 - Micro Trace Buffer (MTB)
- **Pre-Programmed UART Bootloader**
- **Wide Operating Range**
 - 1.8 V to 3.8 V single power supply
 - Integrated DC-DC, down to 1.8 V output with up to 200 mA load current for system
 - Standard (-40 °C to 85 °C T_A) and Extended (-40 °C to 125 °C T_J) temperature grades available
- **Packages**
 - QFN32 (5x5 mm)
 - TQFP48 (7x7 mm)
 - QFN64 (9x9 mm)
 - TQFP64 (10x10 mm)
 - QFN80 (9x9 mm)
 - TQFP80 (12x12 mm)

Ordering Code	Flash (kB)	RAM (kB)	DC-DC Converter	LCD	GPIO	Package	Temp Range
EFM32TG11B320F128GQ48-A	128	32	No	Yes	37	QFP48	-40 to +85°C
EFM32TG11B320F128IQ48-A	128	32	No	Yes	37	QFP48	-40 to +125°C
EFM32TG11B340F64GQ48-A	64	32	No	Yes	37	QFP48	-40 to +85°C
EFM32TG11B340F64IQ48-A	64	32	No	Yes	37	QFP48	-40 to +125°C
EFM32TG11B120F128GM64-A	128	32	No	No	56	QFN64	-40 to +85°C
EFM32TG11B120F128GQ64-A	128	32	No	No	53	QFP64	-40 to +85°C
EFM32TG11B120F128IM64-A	128	32	No	No	56	QFN64	-40 to +125°C
EFM32TG11B120F128IQ64-A	128	32	No	No	53	QFP64	-40 to +125°C
EFM32TG11B140F64GM64-A	64	32	No	No	56	QFN64	-40 to +85°C
EFM32TG11B140F64GQ64-A	64	32	No	No	53	QFP64	-40 to +85°C
EFM32TG11B140F64IM64-A	64	32	No	No	56	QFN64	-40 to +125°C
EFM32TG11B140F64IQ64-A	64	32	No	No	53	QFP64	-40 to +125°C
EFM32TG11B120F128GQ48-A	128	32	No	No	37	QFP48	-40 to +85°C
EFM32TG11B120F128IQ48-A	128	32	No	No	37	QFP48	-40 to +125°C
EFM32TG11B140F64GQ48-A	64	32	No	No	37	QFP48	-40 to +85°C
EFM32TG11B140F64IQ48-A	64	32	No	No	37	QFP48	-40 to +125°C
EFM32TG11B120F128GM32-A	128	32	No	No	24	QFN32	-40 to +85°C
EFM32TG11B120F128IM32-A	128	32	No	No	24	QFN32	-40 to +125°C
EFM32TG11B140F64GM32-A	64	32	No	No	24	QFN32	-40 to +85°C
EFM32TG11B140F64IM32-A	64	32	No	No	24	QFN32	-40 to +125°C

4. Electrical Specifications

4.1 Electrical Characteristics

All electrical parameters in all tables are specified under the following conditions, unless stated otherwise:

- Typical values are based on $T_{AMB}=25^{\circ}\text{C}$ and $V_{DD}=3.3\text{ V}$, by production test and/or technology characterization.
- Minimum and maximum values represent the worst conditions across supply voltage, process variation, and operating temperature, unless stated otherwise.

Refer to [4.1.2.1 General Operating Conditions](#) for more details about operational supply and temperature limits.

4.1.1 Absolute Maximum Ratings

Stresses above those listed below may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. For more information on the available quality and reliability data, see the Quality and Reliability Monitor Report at <http://www.silabs.com/support/quality/pages/default.aspx>.

Table 4.1. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Storage temperature range	T_{STG}		-50	—	150	$^{\circ}\text{C}$
Voltage on any supply pin	V_{DDMAX}		-0.3	—	3.8	V
Voltage ramp rate on any supply pin	$V_{DDRAMP MAX}$		—	—	1	V / μs
DC voltage on any GPIO pin	V_{DIGPIN}	5V tolerant GPIO pins ^{1 2 3}	-0.3	—	Min of 5.25 and IOVDD +2	V
		LCD pins ³	-0.3	—	Min of 3.8 and IOVDD +2	V
		Standard GPIO pins	-0.3	—	IOVDD+0.3	V
Total current into VDD power lines	I_{VDDMAX}	Source	—	—	200	mA
Total current into VSS ground lines	I_{VSSMAX}	Sink	—	—	200	mA
Current per I/O pin	I_{IOMAX}	Sink	—	—	50	mA
		Source	—	—	50	mA
Current for all I/O pins	$I_{IOALLMAX}$	Sink	—	—	200	mA
		Source	—	—	200	mA
Junction temperature	T_J	-G grade devices	-40	—	105	$^{\circ}\text{C}$
		-I grade devices	-40	—	125	$^{\circ}\text{C}$

Note:

1. When a GPIO pin is routed to the analog module through the APORT, the maximum voltage = IOVDD.
2. Valid for IOVDD in valid operating range or when IOVDD is undriven (high-Z). If IOVDD is connected to a low-impedance source below the valid operating range (e.g. IOVDD shorted to VSS), the pin voltage maximum is IOVDD + 0.3 V, to avoid exceeding the maximum IO current specifications.
3. To operate above the IOVDD supply rail, over-voltage tolerance must be enabled according to the GPIO_Px_OVTDIS register. Pins with over-voltage tolerance disabled have the same limits as Standard GPIO.

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Current consumption of peripheral power domain 1, with voltage scaling enabled, DCDC in LP mode ³	I _{PD1_VS}	Additional current consumption in EM2/3 when any peripherals on power domain 1 are enabled ⁴	—	0.18	—	μA
Current consumption of peripheral power domain 2, with voltage scaling enabled, DCDC in LP mode ³	I _{PD2_VS}	Additional current consumption in EM2/3 when any peripherals on power domain 2 are enabled ⁴	—	0.18	—	μA

Note:

1. DCDC Low Noise CCM Mode = Light Drive (PFETCNT=NFETCNT=3), F=6.4 MHz (RCOBAND=4), ANASW=DVDD.
2. DCDC Low Noise DCM Mode = Light Drive (PFETCNT=NFETCNT=3), F=3.0 MHz (RCOBAND=0), ANASW=DVDD.
3. DCDC Low Power Mode = Medium Drive (PFETCNT=NFETCNT=7), LPOSCDIV=1, LPCMPBIASEM234H=0, LPCLIMILIMSEL=1, ANASW=DVDD.
4. Extra current consumed by power domain. Does not include current associated with the enabled peripherals. See [3.2.3 EM2 and EM3 Power Domains](#) for a list of the peripherals in each power domain.
5. CMU_LFRCTRL_ENVREF = 1, CMU_LFRCTRL_VREFUPDATE = 1

4.1.9.2 High-Frequency Crystal Oscillator (HFXO)

Table 4.12. High-Frequency Crystal Oscillator (HFXO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Crystal frequency	f_{HFXO}		4	—	48	MHz
Supported crystal equivalent series resistance (ESR)	ESR_{HFXO}	48 MHz crystal	—	—	50	Ω
		24 MHz crystal	—	—	150	Ω
		4 MHz crystal	—	—	180	Ω
Supported range of crystal load capacitance ¹	$C_{\text{HFXO_CL}}$		TBD	—	TBD	pF
Nominal on-chip tuning cap range ²	$C_{\text{HFXO_T}}$	On each of HFXTAL_N and HFXTAL_P pins	8.7	—	51.7	pF
On-chip tuning capacitance step	SS_{HFXO}		—	0.08	—	pF
Startup time	t_{HFXO}	48 MHz crystal, ESR = 50 Ohm, $C_L = 8$ pF	—	350	—	μs
		24 MHz crystal, ESR = 150 Ohm, $C_L = 6$ pF	—	700	—	μs
		4 MHz crystal, ESR = 180 Ohm, $C_L = 18$ pF	—	3	—	ms
Current consumption after startup	I_{HFXO}	48 MHz crystal	—	880	—	μA
		24 MHz crystal	—	420	—	μA
		4 MHz crystal	—	80	—	μA

Note:

1. Total load capacitance as seen by the crystal.
2. The effective load capacitance seen by the crystal will be $C_{\text{HFXO_T}}/2$. This is because each XTAL pin has a tuning cap and the two caps will be seen in series by the crystal.

4.1.11 General-Purpose I/O (GPIO)

Table 4.18. General-Purpose I/O (GPIO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Input low voltage	V_{IL}	GPIO pins	—	—	$IOVDD \cdot 0.3$	V
Input high voltage	V_{IH}	GPIO pins	$IOVDD \cdot 0.7$	—	—	V
Output high voltage relative to IOVDD	V_{OH}	Sourcing 3 mA, $IOVDD \geq 3$ V, DRIVESTRENGTH ¹ = WEAK	$IOVDD \cdot 0.8$	—	—	V
		Sourcing 1.2 mA, $IOVDD \geq 1.62$ V, DRIVESTRENGTH ¹ = WEAK	$IOVDD \cdot 0.6$	—	—	V
		Sourcing 20 mA, $IOVDD \geq 3$ V, DRIVESTRENGTH ¹ = STRONG	$IOVDD \cdot 0.8$	—	—	V
		Sourcing 8 mA, $IOVDD \geq 1.62$ V, DRIVESTRENGTH ¹ = STRONG	$IOVDD \cdot 0.6$	—	—	V
Output low voltage relative to IOVDD	V_{OL}	Sinking 3 mA, $IOVDD \geq 3$ V, DRIVESTRENGTH ¹ = WEAK	—	—	$IOVDD \cdot 0.2$	V
		Sinking 1.2 mA, $IOVDD \geq 1.62$ V, DRIVESTRENGTH ¹ = WEAK	—	—	$IOVDD \cdot 0.4$	V
		Sinking 20 mA, $IOVDD \geq 3$ V, DRIVESTRENGTH ¹ = STRONG	—	—	$IOVDD \cdot 0.2$	V
		Sinking 8 mA, $IOVDD \geq 1.62$ V, DRIVESTRENGTH ¹ = STRONG	—	—	$IOVDD \cdot 0.4$	V
Input leakage current	I_{IOLEAK}	All GPIO except LFXO pins, GPIO $\leq IOVDD$, $T \leq 85$ °C	—	0.1	TBD	nA
		LFXO Pins, GPIO $\leq IOVDD$, $T \leq 85$ °C	—	0.1	TBD	nA
		All GPIO except LFXO pins, GPIO $\leq IOVDD$, $T > 85$ °C	—	—	TBD	nA
		LFXO Pins, GPIO $\leq IOVDD$, $T > 85$ °C	—	—	TBD	nA
Input leakage current on 5VTOL pads above IOVDD	$I_{5VTOLLEAK}$	$IOVDD < GPIO \leq IOVDD + 2$ V	—	3.3	TBD	μA
I/O pin pull-up/pull-down resistor	R_{PUD}		TBD	40	TBD	kΩ
Pulse width of pulses removed by the glitch suppression filter	$t_{IOGLITCH}$		TBD	25	TBD	ns

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Note: <ol style="list-style-type: none"> Specified configuration for 3X-Gain configuration is: INCBW = 1, HCMDIS = 1, RESINSEL = VSS, $V_{\text{INPUT}} = 0.5 \text{ V}$, $V_{\text{OUTPUT}} = 1.5 \text{ V}$. Nominal voltage gain is 3. If the maximum C_{LOAD} is exceeded, an isolation resistor is required for stability. See AN0038 for more information. When INCBW is set to 1 the OPAMP bandwidth is increased. This is allowed only when the non-inverting close-loop gain is ≥ 3, or the OPAMP may not be stable. Current into the load resistor is excluded. When the OPAMP is connected with closed-loop gain > 1, there will be extra current to drive the resistor feedback network. The internal resistor feedback network has total resistance of 143.5 kOhm, which will cause another $\sim 10 \mu\text{A}$ current when the OPAMP drives 1.5 V between output and ground. Step between 0.2V and $V_{\text{OPA}} - 0.2\text{V}$, 10%-90% rising/falling range. From enable to output settled. In sample-and-off mode, RC network after OPAMP will contribute extra delay. Settling error $< 1\text{mV}$. In unit gain connection, UGF is the gain-bandwidth product of the OPAMP. In 3x Gain connection, UGF is the gain-bandwidth product of the OPAMP and 1/3 attenuation of the feedback network. Specified configuration for Unit gain buffer configuration is: INCBW = 0, HCMDIS = 0, RESINSEL = DISABLE. $V_{\text{INPUT}} = 0.5 \text{ V}$, $V_{\text{OUTPUT}} = 0.5 \text{ V}$. When HCMDIS=1 and input common mode transitions the region from $V_{\text{OPA}} - 1.4\text{V}$ to $V_{\text{OPA}} - 1\text{V}$, input offset will change. PSRR and CMRR specifications do not apply to this transition region. 						

4.1.18 LCD Driver

Table 4.25. LCD Driver

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frame rate	f_{LCDFR}		TBD	—	TBD	Hz
LCD supply range ²	V_{LCDIN}		1.8	—	3.8	V
LCD output voltage range	V_{LCD}	Current source mode, No external LCD capacitor	2.0	—	$V_{\text{LCDIN}} - 0.4$	V
		Step-down mode with external LCD capacitor	2.0	—	V_{LCDIN}	V
		Charge pump mode with external LCD capacitor	2.0	—	Min of 3.8 and 1.9 * V_{LCDIN}	V
Contrast control step size	$\text{STEP}_{\text{CONTRAST}}$	Current source mode	—	64	—	mV
		Charge pump or Step-down mode	—	43	—	mV
Contrast control step accuracy ¹	$\text{ACC}_{\text{CONTRAST}}$		—	+/-4	—	%
Note: <ol style="list-style-type: none"> Step size accuracy is measured relative to the typical step size, and typ value represents one standard deviation. V_{LCDIN} is selectable between the AVDD or DVDD supply pins, depending on EMU_PWRCTRL_ANASW. 						

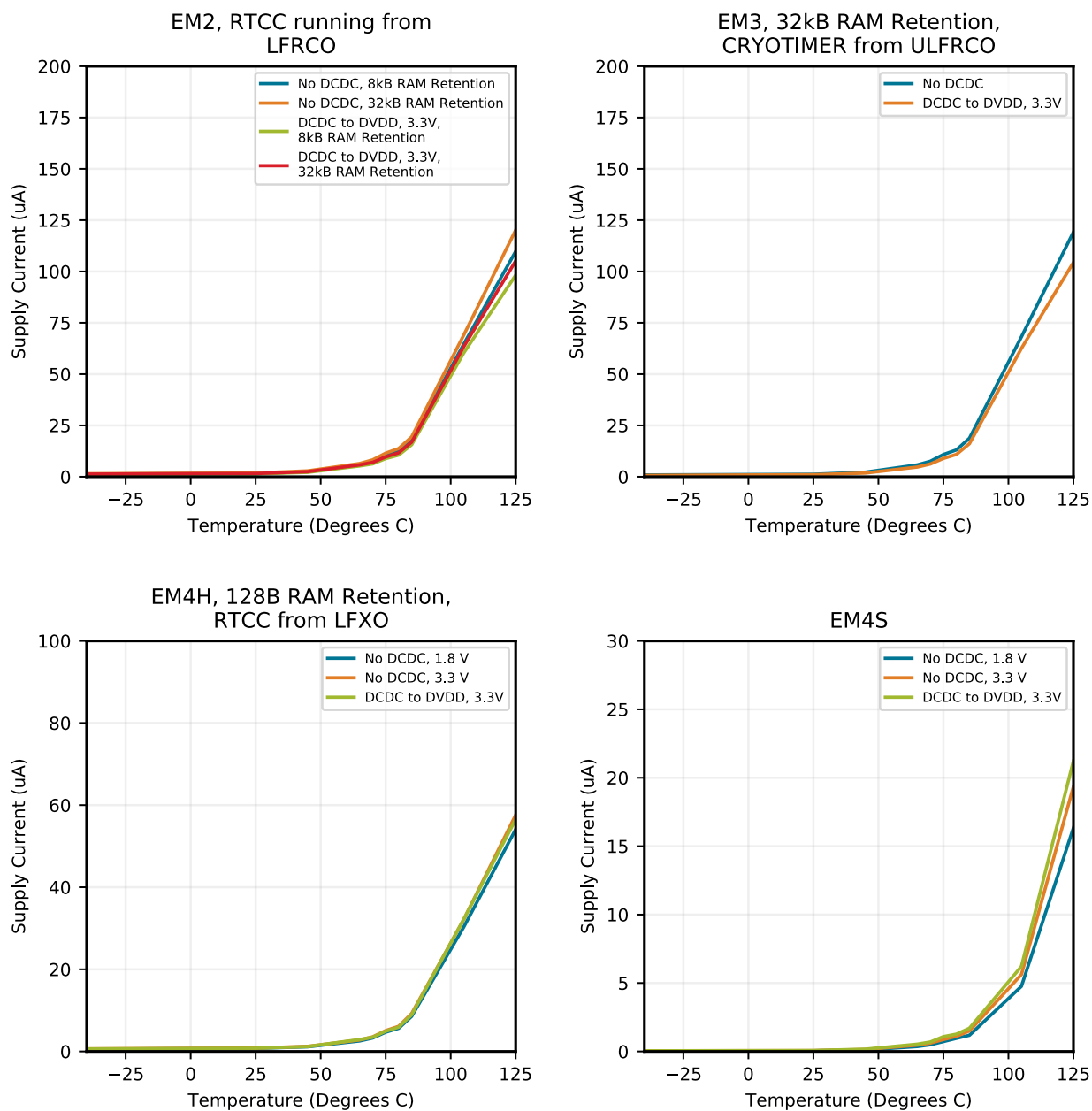


Figure 4.5. EM2, EM3, EM4H and EM4S Typical Supply Current vs. Temperature

4.2.2 DC-DC Converter

Default test conditions: CCM mode, LDCDC = 4.7 μ H, CDCDC = 4.7 μ F, VDCDC_I = 3.3 V, VDCDC_O = 1.8 V, FDCDC_LN = 7 MHz

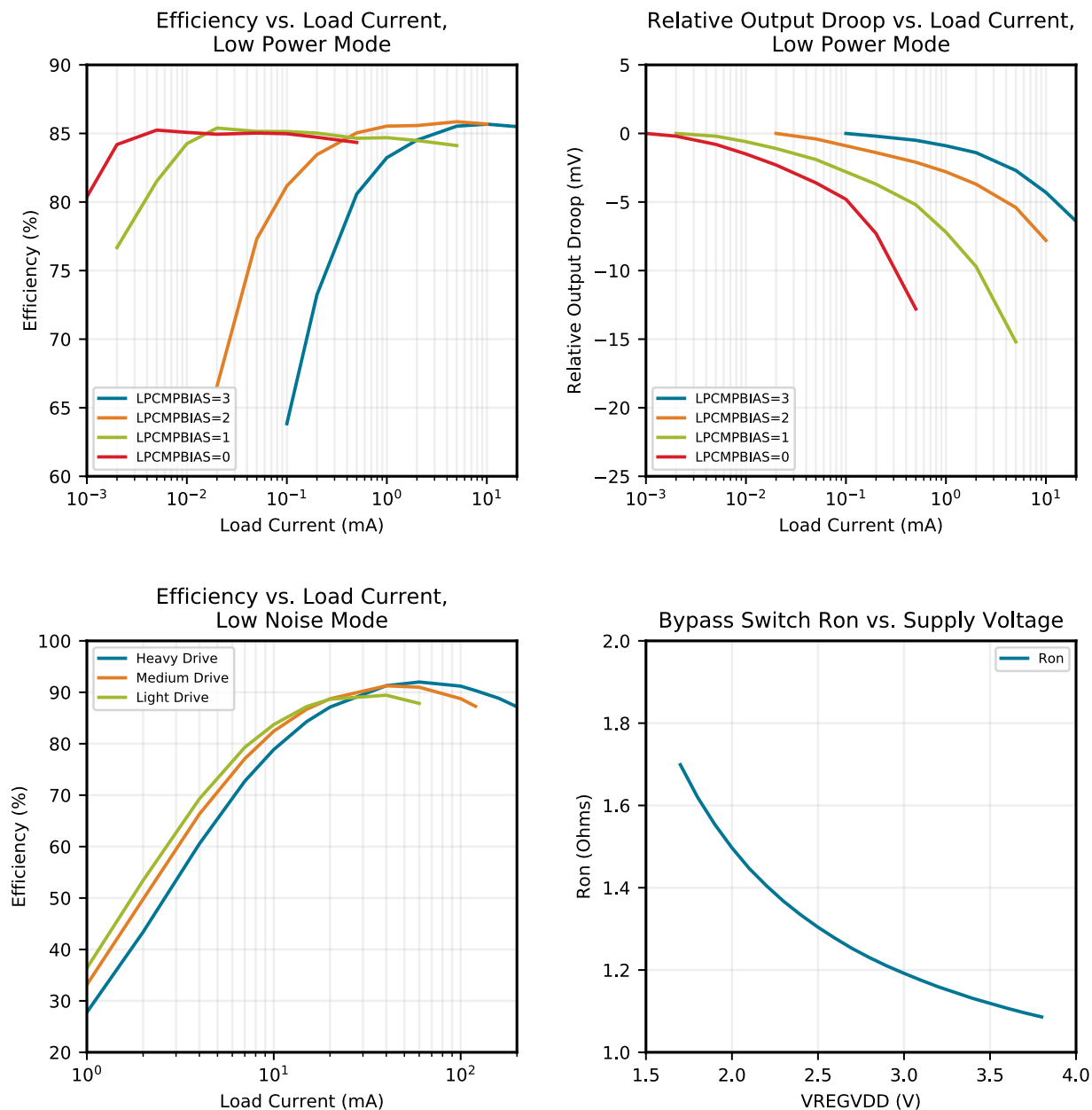


Figure 4.8. DC-DC Converter Typical Performance Characteristics

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PC4	13	GPIO	PC5	14	GPIO
PB7	15	GPIO	PB8	16	GPIO
PA12	17	GPIO	PA13	18	GPIO (5V)
PA14	19	GPIO	RESETn	20	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	21	GPIO	AVDD	23 27	Analog power supply.
PB13	24	GPIO	PB14	25	GPIO
PD0	28	GPIO (5V)	PD1	29	GPIO
PD2	30	GPIO (5V)	PD3	31	GPIO
PD4	32	GPIO	PD5	33	GPIO
PD6	34	GPIO	PD7	35	GPIO
PD8	36	GPIO	PC6	37	GPIO
PC7	38	GPIO	DVDD	39	Digital power supply.
DECOUPLE	40	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PE4	41	GPIO
PE5	42	GPIO	PE6	43	GPIO
PE7	44	GPIO	PC12	45	GPIO (5V)
PC13	46	GPIO (5V)	PC14	47	GPIO (5V)
PC15	48	GPIO (5V)	PF0	49	GPIO (5V)
PF1	50	GPIO (5V)	PF2	51	GPIO
PF3	52	GPIO	PF4	53	GPIO
PF5	54	GPIO	PE8	57	GPIO
PE9	58	GPIO	PE10	59	GPIO
PE11	60	GPIO	PE12	61	GPIO
PE13	62	GPIO	PE14	63	GPIO
PE15	64	GPIO			

Note:

1. GPIO with 5V tolerance are indicated by (5V).

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB6	12	GPIO	PC4	13	GPIO
PC5	14	GPIO	PB7	15	GPIO
PB8	16	GPIO	PA12	17	GPIO
PA13	18	GPIO (5V)	PA14	19	GPIO
RESETn	20	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.	PB11	21	GPIO
PB12	22	GPIO	AVDD	23 27	Analog power supply.
PB13	24	GPIO	PB14	25	GPIO
PD0	28	GPIO (5V)	PD1	29	GPIO
PD2	30	GPIO (5V)	PD3	31	GPIO
PD4	32	GPIO	PD5	33	GPIO
PD6	34	GPIO	PD7	35	GPIO
PD8	36	GPIO	PC6	37	GPIO
PC7	38	GPIO	DVDD	39	Digital power supply.
DECOUPLE	40	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.	PE4	41	GPIO
PE5	42	GPIO	PE6	43	GPIO
PE7	44	GPIO	PC12	45	GPIO (5V)
PC13	46	GPIO (5V)	PC14	47	GPIO (5V)
PC15	48	GPIO (5V)	PF0	49	GPIO (5V)
PF1	50	GPIO (5V)	PF2	51	GPIO
PF3	52	GPIO	PF4	53	GPIO
PF5	54	GPIO	PE8	56	GPIO
PE9	57	GPIO	PE10	58	GPIO
PE11	59	GPIO	PE12	60	GPIO
PE13	61	GPIO	PE14	62	GPIO
PE15	63	GPIO	PA15	64	GPIO

Note:

1. GPIO with 5V tolerance are indicated by (5V).

5.11 EFM32TG11B1xx in QFP48 Device Pinout

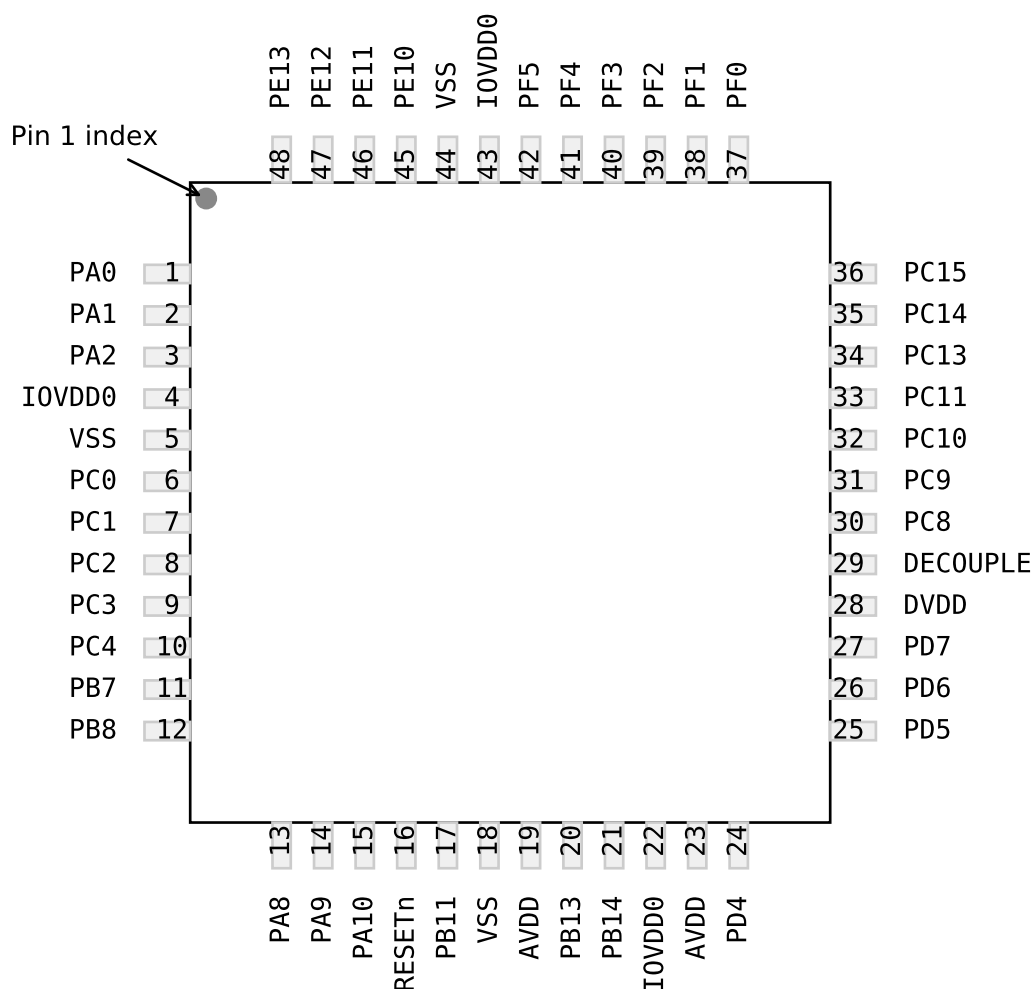


Figure 5.11. EFM32TG11B1xx in QFP48 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see [5.14 GPIO Functionality Table](#) or [5.15 Alternate Functionality Overview](#).

Table 5.11. EFM32TG11B1xx in QFP48 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	IOVDD0	4 22 43	Digital IO power supply 0.
VSS	5 18 44	Ground	PC0	6	GPIO (5V)
PC1	7	GPIO (5V)	PC2	8	GPIO (5V)
PC3	9	GPIO (5V)	PC4	10	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB8	8	GPIO	RESETn	9	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	10	GPIO	AVDD	11 15	Analog power supply.
PB13	12	GPIO	PB14	13	GPIO
PD4	16	GPIO	PD5	17	GPIO
PD6	18	GPIO	PD7	19	GPIO
DVDD	20	Digital power supply.	DECOUPLE	21	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.
PC13	22	GPIO (5V)	PC14	23	GPIO (5V)
PC15	24	GPIO (5V)	PF0	25	GPIO (5V)
PF1	26	GPIO (5V)	PF2	27	GPIO
PE10	29	GPIO	PE11	30	GPIO
PE12	31	GPIO	PE13	32	GPIO
Note: 1. GPIO with 5V tolerance are indicated by (5V).					

GPIO Name	Pin Alternate Functionality / Description			
	Analog	Timers	Communication	Other
PC4	BUSACMP0Y BU-SACMP0X OPA0_P LCD_SEG24	TIM0_CC0 #5 TIM0_CDTI2 #3 LE-TIM0_OUT0 #3	US2_CLK #0 U0_TX #4 I2C1_SDA #0	LES_CH4 GPIO_EM4WU6
PC5	BUSACMP0Y BU-SACMP0X OPA0_N LCD_SEG25	TIM0_CC1 #5 LE-TIM0_OUT1 #3	US2_CS #0 U0_RX #4 I2C1_SCL #0	LES_CH5
PB7	LFXTAL_P	TIM0_CDTI0 #4 TIM1_CC0 #3	US0_TX #4 US1_CLK #0 US3_RX #2 U0_CTS #4	
PB8	LFXTAL_N	TIM0_CDTI1 #4 TIM1_CC1 #3	US0_RX #4 US1_CS #0 U0_RTS #4	CMU_CLKI0 #2
PA8	BU_STAT	TIM0_CC0 #6 LE-TIM0_OUT0 #6	US2_RX #2	
PA9	BUSAY BUSBX LCD_SEG26	TIM0_CC1 #6 LE-TIM0_OUT1 #6	US2_CLK #2	
PA10	BUSBY BUSAX LCD_SEG27	TIM0_CC2 #6	US2_CS #2	
PA12	BU_VOUT	WTIM0_CDTI0 #2	US0_CLK #5 US2_RTS #2	CMU_CLK0 #5 ACMP1_O #3
PA13	BUSAY BUSBX	TIM0_CC2 #7 WTIM0_CDTI1 #2	US0_CS #5 US2_TX #3	
PA14	BUSBY BUSAX LCD_BEXT	WTIM0_CDTI2 #2	US1_TX #6 US2_RX #3 US3_RTS #2	ACMP1_O #4
PB11	BUSAY BUSBX VDAC0_OUT0 / OPA0_OUT LCD_SEG28	TIM0_CDTI2 #4 TIM1_CC2 #3 LE-TIM0_OUT0 #1 PCNT0_S1IN #7	US0_CTS #5 US1_CLK #5 US2_CS #3 I2C1_SDA #1	CMU_CLK1 #5 CMU_CLKI0 #7 ACMP0_O #3 GPIO_EM4WU7
PB12	BUSBY BUSAX VDAC0_OUT1 / OPA1_OUT LCD_SEG29	TIM1_CC3 #3 LE-TIM0_OUT1 #1 PCNT0_S0IN #7	US2_CTS #1 I2C1_SCL #1	
PB13	BUSAY BUSBX HFXTAL_P	WTIM1_CC0 #0	US0_CLK #4 US1_CTS #5 LEU0_TX #1	CMU_CLKI0 #3 PRS_CH7 #0
PB14	BUSBY BUSAX HFXTAL_N	WTIM1_CC1 #0	US0_CS #4 US1_RTS #5 LEU0_RX #1	PRS_CH6 #1
PD0	VDAC0_OUT0ALT / OPA0_OUTALT #4 OPA2_OUTALT BU-SADC0Y BUSADC0X	WTIM1_CC2 #0	CAN0_RX #2 US1_TX #1	
PD1	VDAC0_OUT1ALT / OPA1_OUTALT #4 BU-SADC0Y BUSADC0X OPA3_OUT	TIM0_CC0 #2 WTIM1_CC3 #0	CAN0_TX #2 US1_RX #1	
PD2	BUSADC0Y BUSADC0X	TIM0_CC1 #2 WTIM1_CC0 #1	US1_CLK #1	
PD3	BUSADC0Y BUSADC0X OPA2_N LCD_SEG30	TIM0_CC2 #2 WTIM1_CC1 #1	US1_CS #1	
PD4	BUSADC0Y BUSADC0X OPA2_P LCD_SEG31	WTIM0_CDTI0 #4 WTIM1_CC2 #1	US1_CTS #1 US3_CLK #2 LEU0_TX #0 I2C1_SDA #3	CMU_CLKI0 #0

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
LCD_COM0	0: PE4		LCD driver common line number 0.
LCD_COM1	0: PE5		LCD driver common line number 1.
LCD_COM2	0: PE6		LCD driver common line number 2.
LCD_COM3	0: PE7		LCD driver common line number 3.
LCD_SEG0	0: PF2		LCD segment line 0.
LCD_SEG1	0: PF3		LCD segment line 1.
LCD_SEG2	0: PF4		LCD segment line 2.
LCD_SEG3	0: PF5		LCD segment line 3.
LCD_SEG4	0: PE8		LCD segment line 4.
LCD_SEG5	0: PE9		LCD segment line 5.
LCD_SEG6	0: PE10		LCD segment line 6.
LCD_SEG7	0: PE11		LCD segment line 7.
LCD_SEG8	0: PE12		LCD segment line 8.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
U0_TX	2: PA3 3: PC14	4: PC4 5: PF1 6: PD7	UART0 Transmit output. Also used as receive input in half duplex communication.
US0_CLK	0: PE12 1: PE5 2: PC9 3: PC15	4: PB13 5: PA12	USART0 clock input / output.
US0_CS	0: PE13 1: PE4 2: PC8 3: PC14	4: PB14 5: PA13	USART0 chip select input / output.
US0_CTS	0: PE14 2: PC7 3: PC13	4: PB6 5: PB11	USART0 Clear To Send hardware flow control input.
US0_RTS	0: PE15 2: PC6 3: PC12	4: PB5 5: PD6	USART0 Request To Send hardware flow control output.
US0_RX	0: PE11 1: PE6 2: PC10 3: PE12	4: PB8 5: PC1	USART0 Asynchronous Receive. USART0 Synchronous mode Master Input / Slave Output (MISO).
US0_TX	0: PE10 1: PE7 2: PC11 3: PE13	4: PB7 5: PC0	USART0 Asynchronous Transmit. Also used as receive input in half duplex communication. USART0 Synchronous mode Master Output / Slave Input (MOSI).
US1_CLK	0: PB7 1: PD2 2: PF0 3: PC15	4: PC3 5: PB11 6: PE5	USART1 clock input / output.
US1_CS	0: PB8 1: PD3 2: PF1 3: PC14	4: PC0 5: PE4	USART1 chip select input / output.
US1_CTS	1: PD4 2: PF3 3: PC6	4: PC12 5: PB13	USART1 Clear To Send hardware flow control input.
US1_RTS	1: PD5 2: PF4 3: PC7	4: PC13 5: PB14	USART1 Request To Send hardware flow control output.
US1_RX	0: PC1 1: PD1 2: PD6	4: PC2 5: PA0 6: PA2	USART1 Asynchronous Receive. USART1 Synchronous mode Master Input / Slave Output (MISO).
US1_TX	0: PC0 1: PD0 2: PD7	4: PC1 5: PF2 6: PA14	USART1 Asynchronous Transmit. Also used as receive input in half duplex communication. USART1 Synchronous mode Master Output / Slave Input (MOSI).

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
US2_CLK	0: PC4 1: PB5 2: PA9 3: PA15	5: PF2	USART2 clock input / output.
US2_CS	0: PC5 1: PB6 2: PA10 3: PB11	5: PF5	USART2 chip select input / output.
US2_CTS	0: PC1 1: PB12	4: PC12 5: PD6	USART2 Clear To Send hardware flow control input.
US2_RTS	0: PC0 2: PA12 3: PC14	4: PC13 5: PD8	USART2 Request To Send hardware flow control output.
US2_RX	0: PC3 1: PB4 2: PA8 3: PA14	5: PF1	USART2 Asynchronous Receive. USART2 Synchronous mode Master Input / Slave Output (MISO).
US2_TX	0: PC2 1: PB3 3: PA13	5: PF0	USART2 Asynchronous Transmit. Also used as receive input in half duplex communication. USART2 Synchronous mode Master Output / Slave Input (MOSI).
US3_CLK	0: PA2 1: PD7 2: PD4		USART3 clock input / output.
US3_CS	0: PA3 1: PE4 2: PC14 3: PC0		USART3 chip select input / output.
US3_CTS	0: PA4 1: PE5 2: PD6		USART3 Clear To Send hardware flow control input.
US3_RTS	0: PA5 1: PC1 2: PA14 3: PC15		USART3 Request To Send hardware flow control output.
US3_RX	0: PA1 1: PE7 2: PB7		USART3 Asynchronous Receive. USART3 Synchronous mode Master Input / Slave Output (MISO).
US3_TX	0: PA0 1: PE6 2: PB3		USART3 Asynchronous Transmit. Also used as receive input in half duplex communication. USART3 Synchronous mode Master Output / Slave Input (MOSI).
VDAC0_EXT	0: PD6		Digital to analog converter VDAC0 external reference input pin.

APORT4Y	APORT3Y	APORT2Y	APORT1Y
BUSDY	BUSCY	BUSBY	BUSAY
		PB14	
			PB13
		PB12	
			PB11
		PB6	
	PF5		PB5
PF4		PB4	
	PF3		PB3
PF2			
	PF1		
PF0			
	PE15		PA15
PE14		PA14	
	PE13		PA13
PE12			
	PE11		
PE10		PA10	
	PE9		PA9
PE8			
	PE7		
PE6		PA6	
	PE5		PA5
PE4		PA4	
			PA3
		PA2	
			PA1
		PA0	

8. TQFP64 Package Specifications

8.1 TQFP64 Package Dimensions

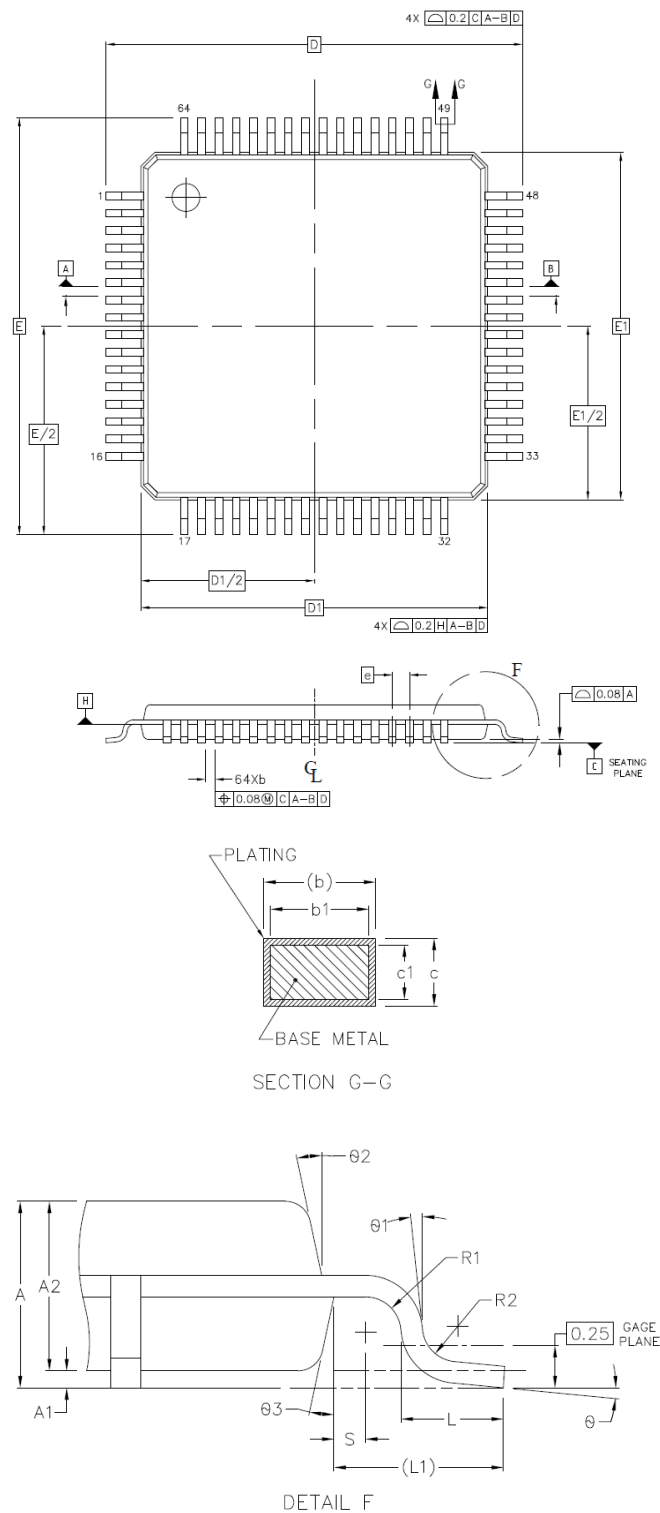


Figure 8.1. TQFP64 Package Drawing

10.3 TQFP48 Package Marking



Figure 10.3. TQFP48 Package Marking

The package marking consists of:

- P P P P P P P P P P – The part number designation.
- T T T T T T – A trace or manufacturing code. The first letter is the device revision.
- Y Y – The last 2 digits of the assembly year.
- W W – The 2-digit workweek when the device was assembled.